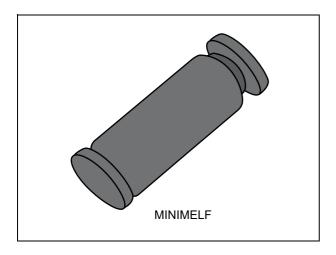


TMMBAT42 - TMMBAT43

Small signal Schottky diodes

Datasheet - production data



Description

General purpose metal to silicon diode featuring very low turn-on voltage and fast switching.

These devices have integrated protection against excessive voltage such as electrostatic discharges.

Features

- Very small conduction losses
- Negligible switching losses
- Low forward voltage drop

This is information on a product in full production.

1 Characteristics

Table 1. Absolute maximum ratings at 25 °C unless otherwise specified

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	30	V
I _F	Forward continuous current	200	mA
I _{FRM}	Repetitive peak forward current	500	mA
I _{FSM}	Surge non repetitive forward current	4	Α
P _{tot}	Power dissipation	200	mW
T _{stg}	Storage temperature range	-65 to + 150	°C
Tj	Operating junction temperature range	-65 to + 125	°C
T _L	Maximum temperature for soldering during 15 s	260	°C

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to leads	300	°C/W

Table 3. Static electrical characteristics

Symbol	Test conditions			Тур.	Max.	Unit
V_{BR}	$T_j = 25 ^{\circ}\text{C}; I_{R} = 100 \mu\text{A}$			-		V
V _F ⁽¹⁾	$T_j = 25 ^{\circ}\text{C}; I_F = 200 \text{mA}$	All types		-	1	
	$T_j = 25 ^{\circ}\text{C}; I_F = 10 \text{mA}$	TMMBAT42FILM		-	0.4	
	$T_j = 25 ^{\circ}\text{C}; I_F = 50 \text{mA}$	TIVIIVIDAT42FILIVI		-	0.65	V
	T _j = 25 °C; I _F = 2 mA	I _F = 2 mA TMMBAT43FILM	0.26	-	0.33	
	$T_j = 25 ^{\circ}\text{C}; I_F = 15 \text{mA}$	TIVIIVIDAT 43FILIVI		-	0.45	
I _R ⁽¹⁾	$T_j = 25 ^{\circ}\text{C}, V_R = 25 \text{V}$			-	0.5	
	T _j = 100 °C, V _R = 25 V		-	100	μA	

^{1.} Pulse test: $t_p = 380 \,\mu s \, \delta < 2\%$

Table 4. Dynamic characteristics

Symbol	Test conditions		Тур.	Max.	Unit
С	$T_j = 25 \text{ °C}; V_{R=1} V; f = 1 \text{ MHz}$		7		pF
t _{rr}	T_j = 25 °C; I_F =10 mA; I_R = 10 mA; I_{RR} = 1 mA R_L = 100 Ω			5	ns

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1.E-03

1.E-01 (typical values, high level)

Figure 1. Forward voltage drop versus forward

Figure 2. Forward voltage drop versus forward current (typical values)

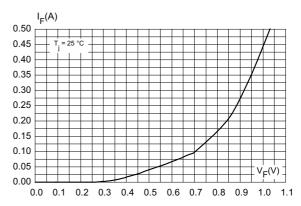


Figure 3. Leakage current versus reverse voltage applied (typical values)

0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 1.3

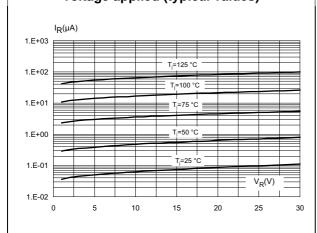
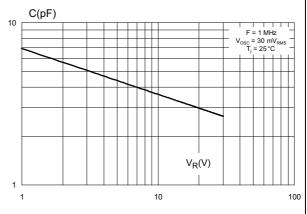


Figure 4. Junction capacitance versus reverse voltage applied (typical values)



2 Package information

• Ring at cathode end.

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 MINIMELF package information

A A ØB

Figure 5. MINIMELF package outline

Table 5. MINIMELF mechanical data

	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	3.30	3.50	3.70	0.130	0.138	0.146
ØB	1.59	1.65	1.70	0.063	0.065	0.069
С	0.40	0.50	0.60	0.016	0.020	0.024
ØD		1.50			0.059	

2.5 5





3 Ordering information

Table 6. Ordering information

Order code	Package	Weight	Base qty	Delivery mode
TMMBAT42FILM	MINIMELF	40 mg	2500	Tape and reel
TMMBAT43FILM	WIIIVIIVIEEF	40 mg	2300	rape and reer

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
Aug-1999	1A	Last issue.
31-Jul-2014	2	Reformatted to current standards. Added ordering information.
27-Jul-2015	3	Updated MINIMELF package information and reformatted to current standard. Updated <i>Figure 1</i> , <i>Figure 2</i> , <i>Figure 3</i> , and <i>Figure 4</i> .

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